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November 2013

FQPF65N06

N-Channel QFET[®] MOSFET 60 V, 40 A, 16 m Ω

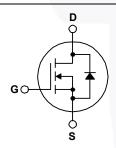
Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

Features

- 40 A, 60 V, $R_{DS(on)}$ = 16 m Ω (Max.) @ V_{GS} = 10 V, I_{D} = 20 A
- Low Gate Charge (Typ. 48 nC)
- Low Crss (Typ. 100 pF)
- · 100% Avalanche Tested
- · 175°C Maximum Junction Temperature Rating





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter		FQPF65N06	Unit	
V _{DSS}	Drain-Source Voltage		60	V	
I _D	Drain Current - Continuous (T _C = 25°C)		40	Α	
	- Continuous (T _C = 100°C)		28.3	Α	
I _{DM}	Drain Current - Pulsed	(Note 1)	160	Α	
V _{GSS}	Gate-Source Voltage		± 25	V	
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	645	mJ	
I _{AR}	Avalanche Current	(Note 1)	40	Α	
E _{AR}	Repetitive Avalanche Energy	(Note 1)	5.6	mJ	
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	7.0	V/ns	
P_D	Power Dissipation (T _C = 25°C)		56	W	
	- Derate above 25°C		0.37	W/°C	
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +175	°C	
T _L	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 seconds		300	°C	

Thermal Characteristics

Symbol	Parameter	FQPF65N06	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	2.66	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	°C/W	

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQPF65N06	FQPF65N06	TO-220F	Tube	N/A	N/A	50 units

Electrical Characteristics

T_C = 25°C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min	Тур	Max	Uni
Off Cha	aracteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	60			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I_D = 250 μA, Referenced to 25°C		0.07		V/°C
I _{DSS}	Zero Osto Valta va Brain Ormant	V _{DS} = 60 V, V _{GS} = 0 V			1	μΑ
Zero Gate Voltage Drain Curre	Zero Gate Voltage Drain Current	V _{DS} = 48 V, T _C = 150°C			10	μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 25 V, V _{DS} = 0 V			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = -25 V, V _{DS} = 0 V			-100	nA
On Cha	aracteristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.0		4.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = 10 V, I _D = 20 A	-	0.0125	0.016	Ω
g _{FS}	Forward Transconductance	V _{DS} = 25 V, I _D = 20 A		40		S
C _{iss}	ic Characteristics Input Capacitance	V _{DS} = 25 V, V _{GS} = 0 V, f = 1.0 MHz		1850	2410	pF
C _{oss}	Output Capacitance			700	910	pF
C _{rss}	Reverse Transfer Capacitance			100	130	pF
Switch	ing Characteristics					
t _{d(on)}	Turn-On Delay Time	$V_{DD} = 30 \text{ V}, I_{D} = 32.5 \text{ A},$		20	50	ns
t _r	Turn-On Rise Time	$V_{DD} = 30 \text{ V}, I_{D} = 32.3 \text{ A},$ $R_{G} = 25 \Omega$		160	330	ns
t _{d(off)}	Turn-Off Delay Time	116 - 20 22		90	190	ns
t _f	Turn-Off Fall Time	(Note 4)		105	220	ns
Qg	Total Gate Charge	V _{DS} = 48 V, I _D = 65 A,		48	65	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 10 V	/	12		nC
Q _{gd}	Gate-Drain Charge	(Note 4)		19.5		nC
	Source Diode Characteristics a	nd Maximum Ratings	•			
I _S	Maximum Continuous Drain-Source Diode Forward Current				40	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current				160	Α
		The state of the s				

Q_{rr}

 V_{SD}

 t_{rr}

Notes: 1. Repetitive Rating : Pulse width limited by maximum junction temperature. 2. L = 470 μ H, I_{AS} = 40 A, V_{DD} = 25 V, R_G = 25 Ω , starting T_J = 25°C. 3. I_{SD} \leq 65 A, di/dt \leq 300 A/ μ s, V_{DD} \leq BV_{DSS}, starting T_J = 25°C. 4. Essentially Independent of Operating Temperature.

Drain-Source Diode Forward Voltage

Reverse Recovery Time

Reverse Recovery Charge

 $V_{GS} = 0 \text{ V}, I_{S} = 40 \text{ A}$

V_{GS} = 0 V, I_S = 65 A,

 $dI_F / dt = 100 A/\mu s$

1.5

62

110

V

ns

nC

Typical Characteristics

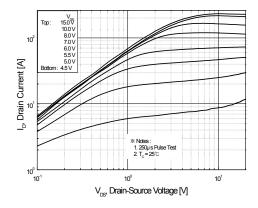


Figure 1. On-Region Characteristics

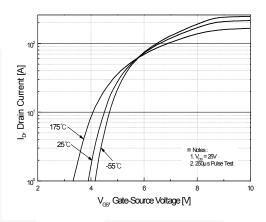


Figure 2. Transfer Characteristics

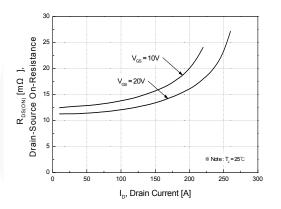


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

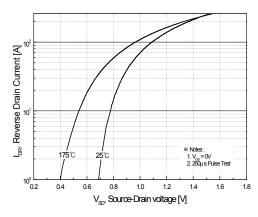


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

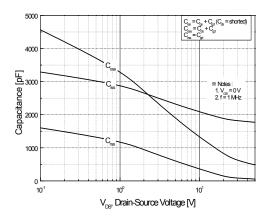


Figure 5. Capacitance Characteristics

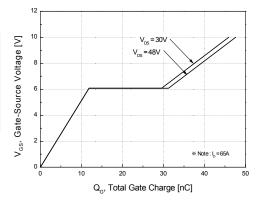


Figure 6. Gate Charge Characteristics

Typical Characteristics (continued)

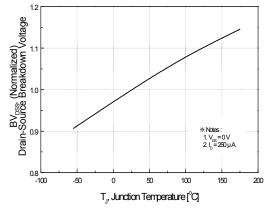


Figure 7. Breakdown Voltage Variation vs. Temperature

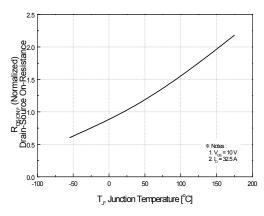


Figure 8. On-Resistance Variation vs. Temperature

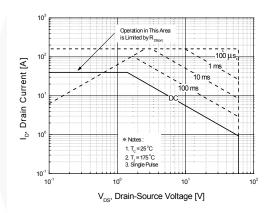


Figure 9. Maximum Safe Operating Area

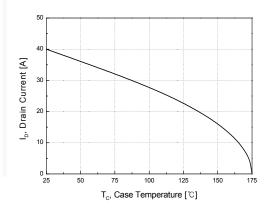


Figure 10. Maximum Drain Current vs. Case Temperature

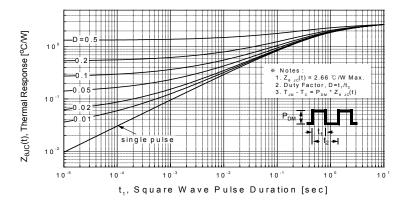


Figure 11. Transient Thermal Response Curve

Figure 12. Gate Charge Test Circuit & Waveform

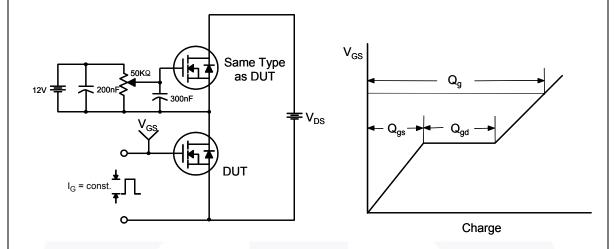


Figure 13. Resistive Switching Test Circuit & Waveforms

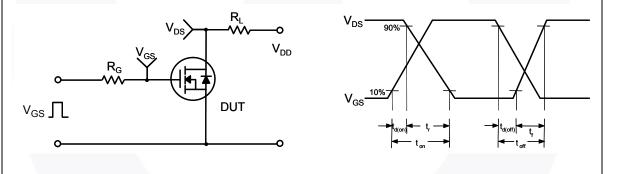
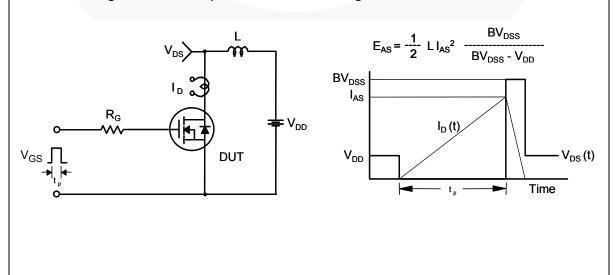
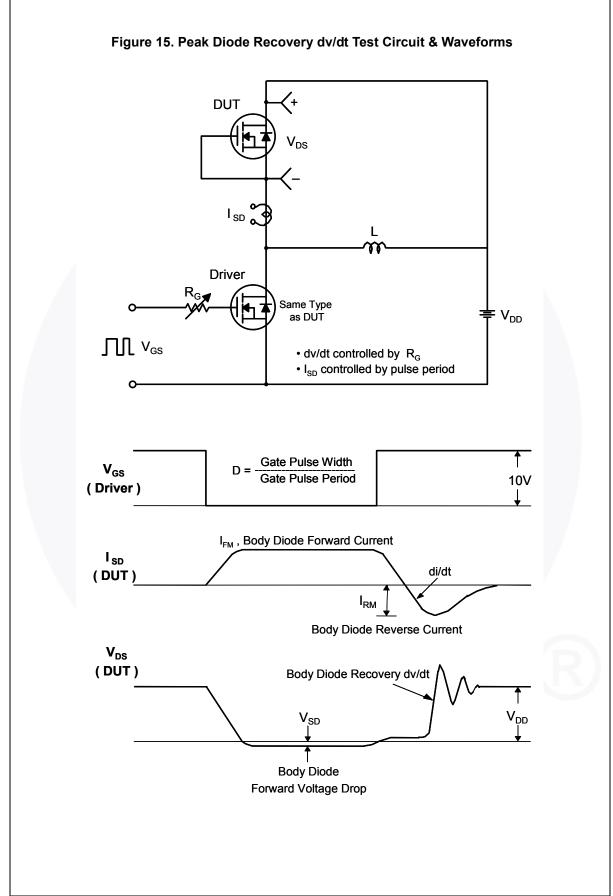


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms





Mechanical Dimensions

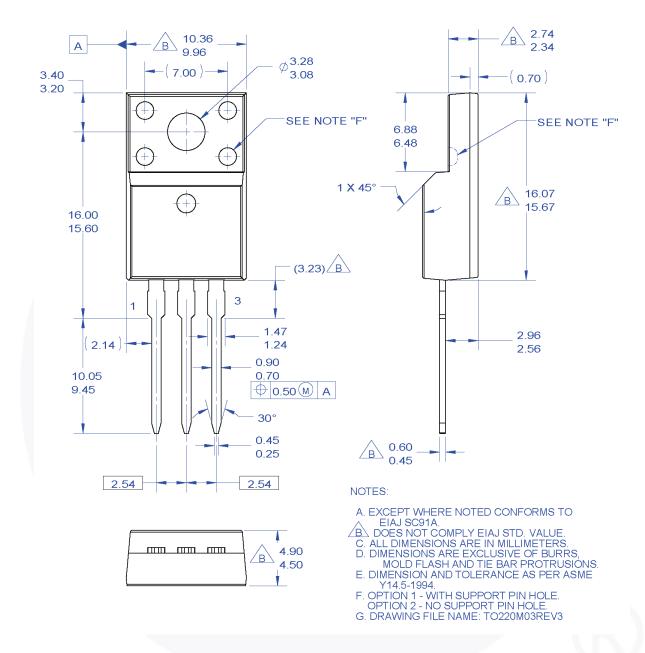


Figure 16. TO220, Molded, 3-Lead, Full Pack, EIAJ SC91, Straight Lead

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